

# BRCS080N04YB

Rev.A Jun.-2022

## / Descriptions

PDFN 3×3A-8L N MOS

N-Channel Enhancement Mode Field Effect Transistor in a PDFN 3×3A-8L Plastic Package.

## / Features

$V_{DS} (V) = 40V$

$I_D = 45 A (V_{GS} = 20V)$

$R_{DS(ON)} @ 10V = 8mR (Typ. 6.4mR)$

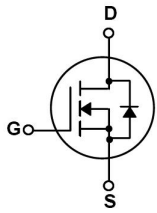
HF Product.

## / Applications

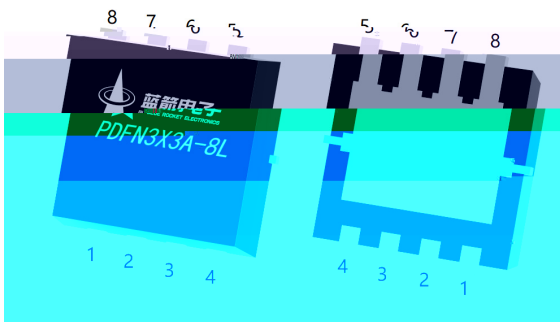
DC/DC

These devices are well suited for high efficiency switching DC/DC converters and switch mode power supplies.

## / Equivalent Circuit



## / Pinning



出脚	定义
Pin1	S
Pin2	S
Pin3	S
Pin4	S
Pin5	S
Pin6	S
Pin7	S
Pin8	S

## / Marking

See Marking Instructions.

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## DATA SHEET

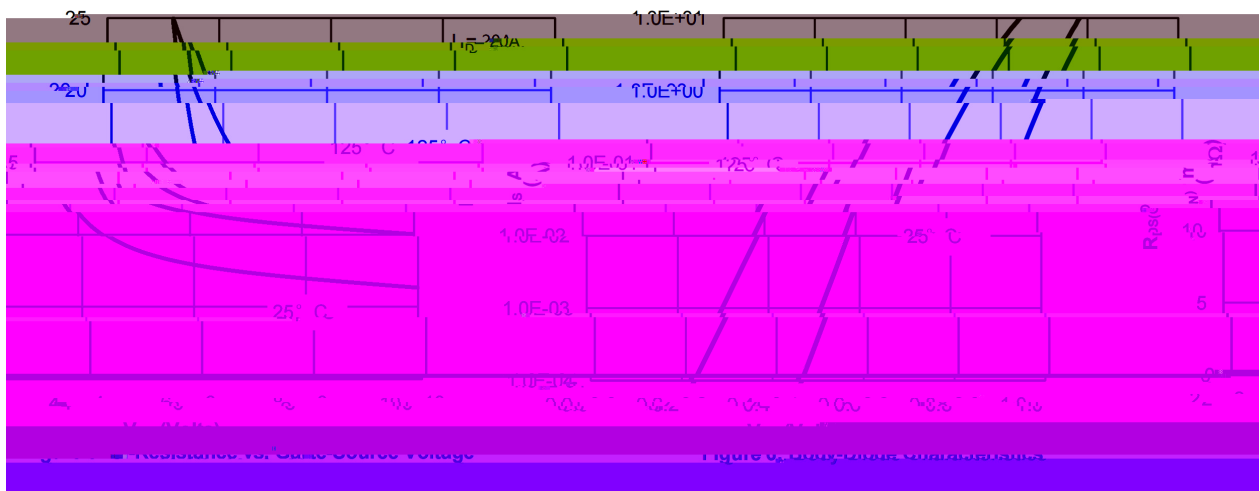
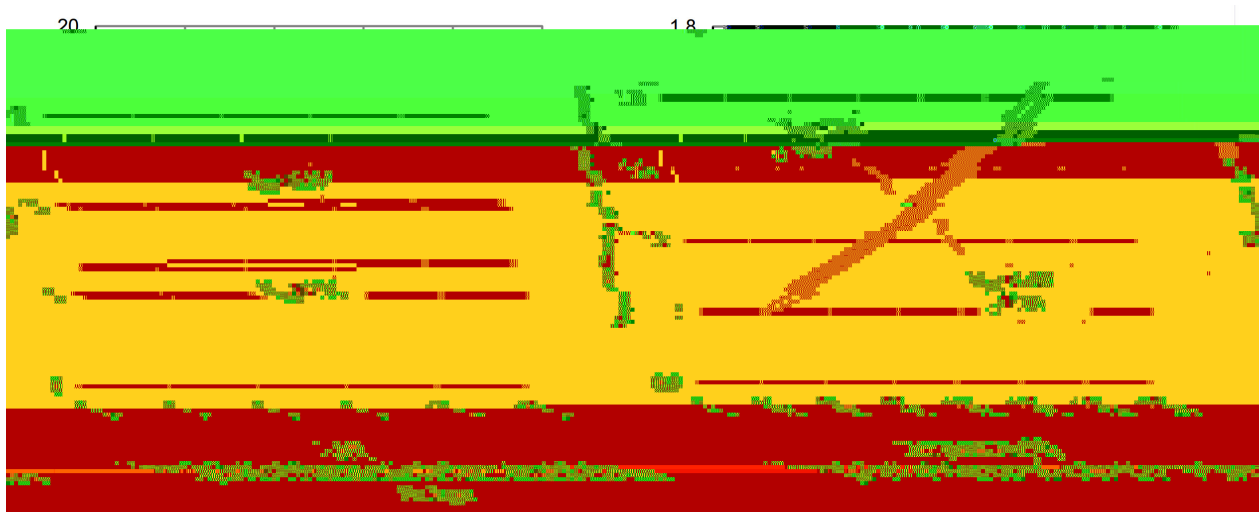
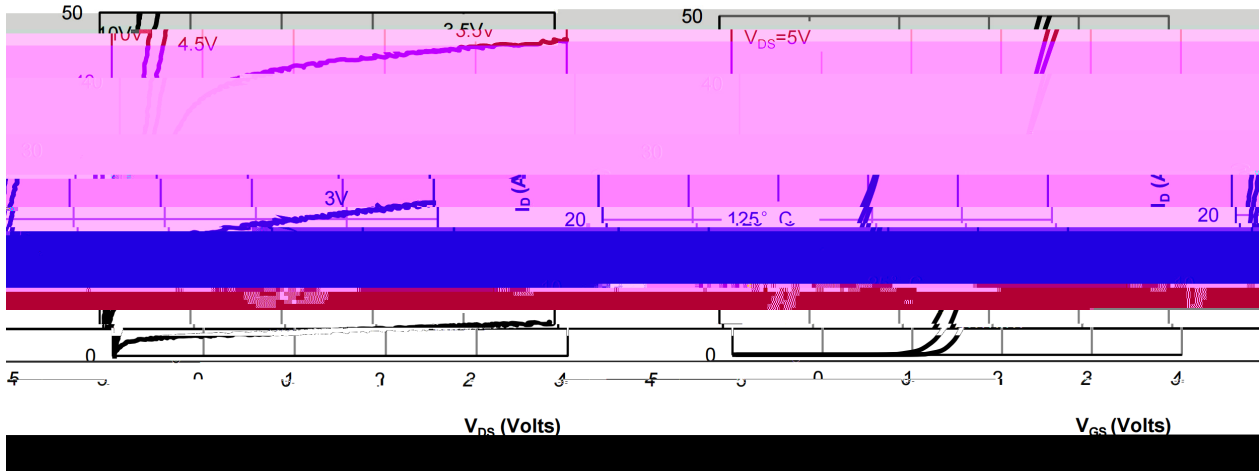
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DSS}$	40	V
Drain Current	$I_D(T_C=25)$	45	A
Drain Current - Pulsed	$I_{DM}$	105	A
Gate-Source Voltage	$V_{GSS}$	$\pm 20$	V
Single Pulsed Avalanche Energy	$E_{AS}$	67.6	mJ
Avalanche Current	$I_{AS}$	13	A
Power Dissipation	$P_D(T_C=25)$	27	W
Operating and Storage Temperature Range	$T_J, T_{stg}$	-55 to 150	

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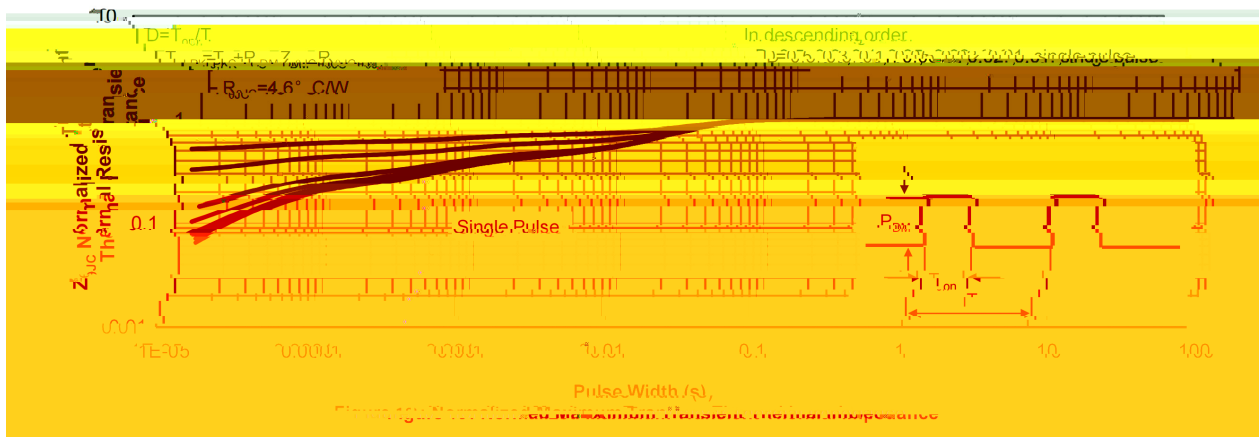
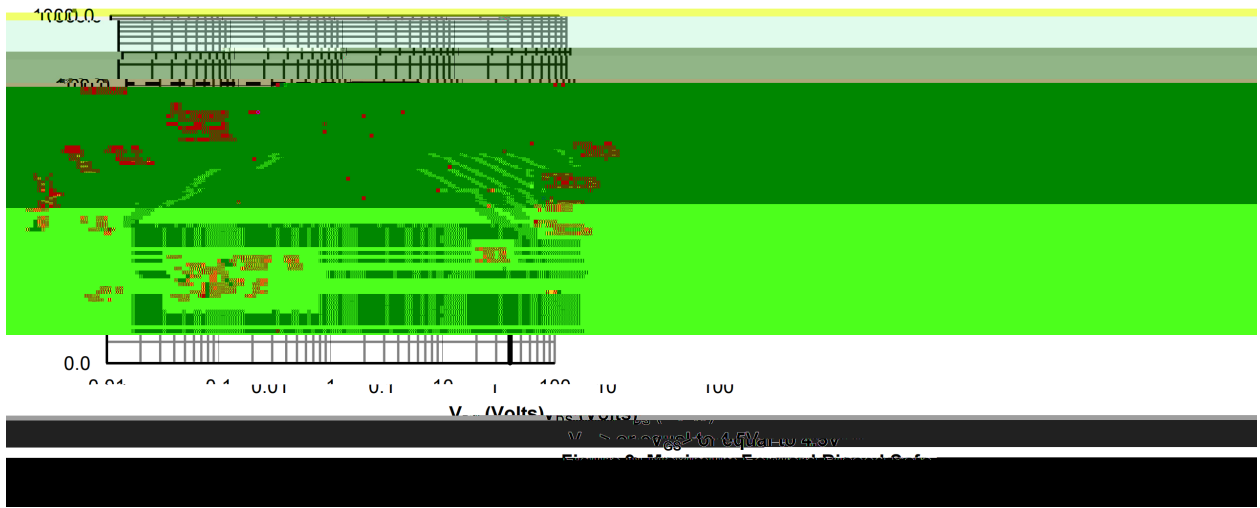
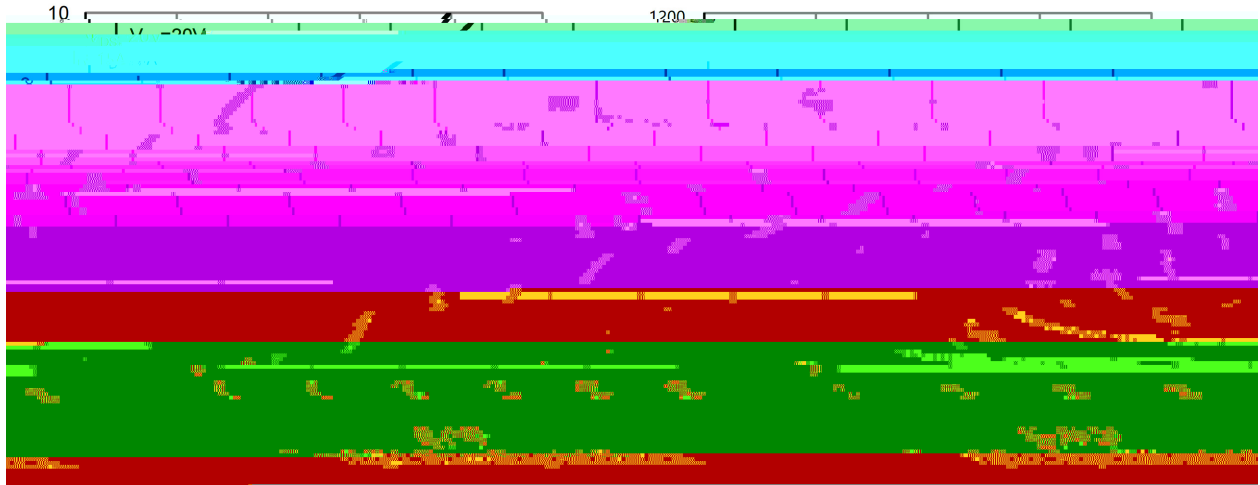
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/ Electrical Characteristic Curve



**/ Electrical Characteristic Curve**



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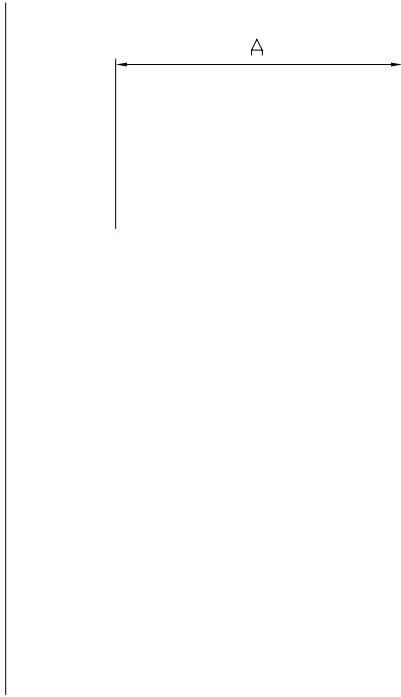


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## / Package Dimensions

PDFN3X3A-8L

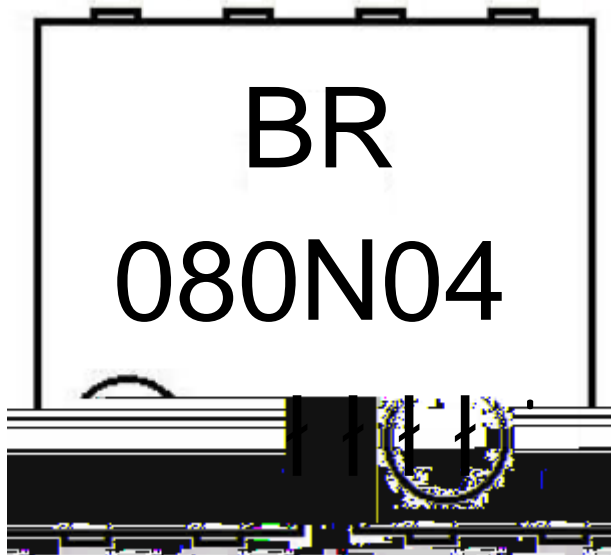
Unit:mm



Dimensions In  
Millimeterer  
Symbol

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**/ Marking Instructions**



BR

080N04

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Note:

BR: Company Code

080N04: Product Type Code

\*\*\*\*: Lot No. Code, code change with Lot No

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## ( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)


Note:

- 1 150 180 60 90sec; 1.Preheating:150~180 , Time:60~90sec.
- 2 245±5 5±0.5sec; 2.Peak Temp.:245±5 , Duration:5±0.5sec.
- 3 2 10 /sec. 3. Cooling Speed: 2~10 /sec.

## / Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

## / Packaging SPEC.

/ REEL

Package Type  
封装形式

Units